

Microelectronics System Design Group

Intra-chip Physical Parameter Sensor for FPGAs using Flip-Flop Metastability

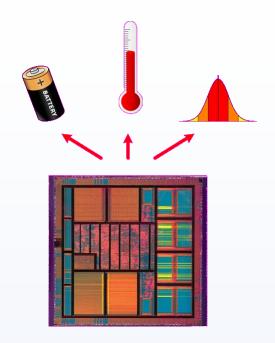
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30th August 2012

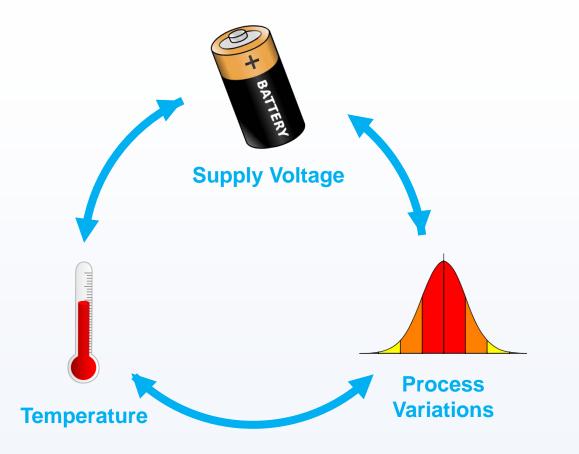
Presentation Overview

- Introduction
- Ring Oscillator Sensing
- Proposed Sensor
- FPGA Measurements
- Conclusion

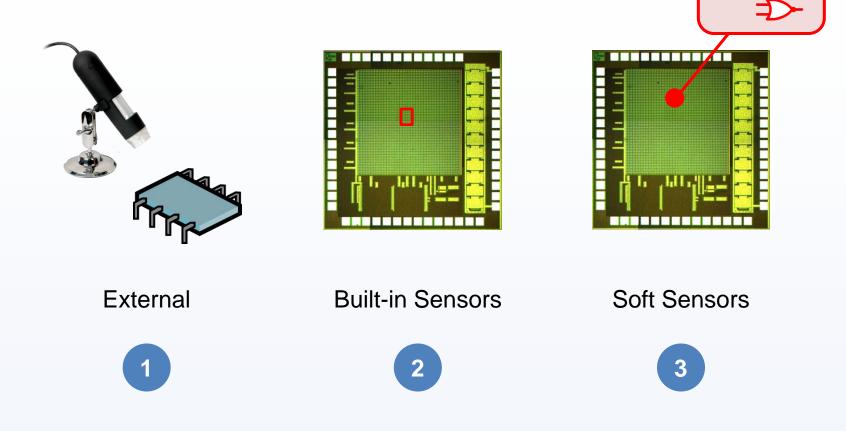
- Physical parameter sensing in FPGAs:
 - 1. Dynamic power and thermal management
 - 2. Development of power and thermal models
 - 3. Variation-aware component placement
 - 4. Monitoring and performance profiling



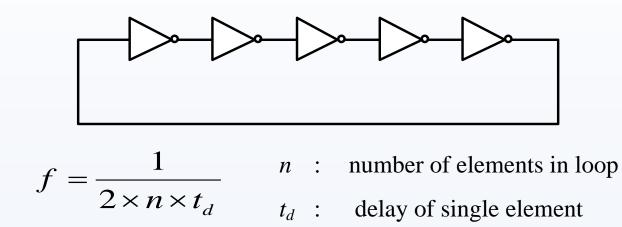
Intra-chip physical parameters are strongly interlinked.



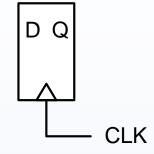
• Physical parameter sensing in FPGAs:



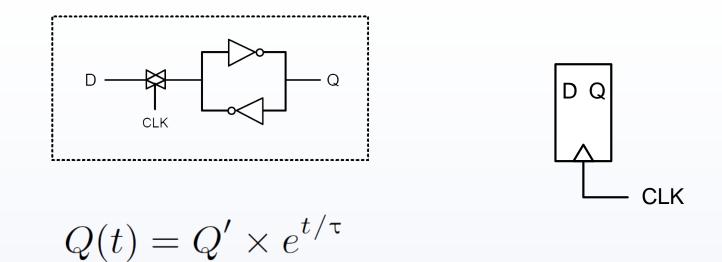
- Ring Oscillators:
 - Oscillation frequency inversely proportional to element delay
 - Higher VDD \rightarrow lower element delay \rightarrow higher frequency



- When the setup and hold time conditions of a flip-flop are not met, the flip-flop may become **metastable**.
- A metastable flip-flop will take extra time to decide whether to go logic high or low.
- Extra decision time = higher clock-to-q delay



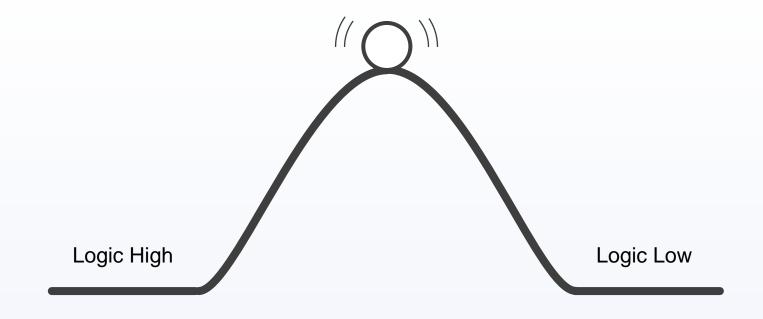
• Flip-flop Metastability:

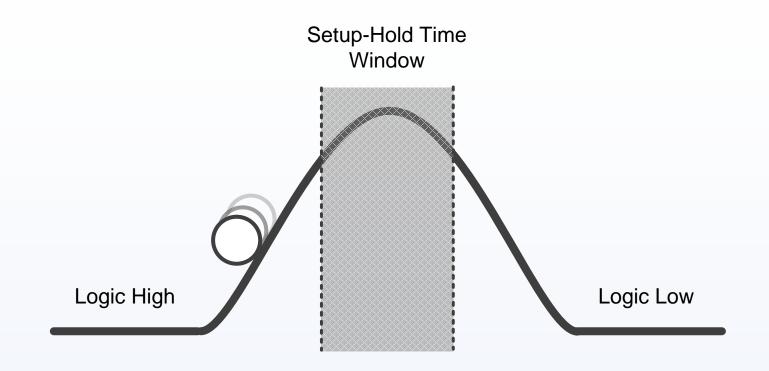


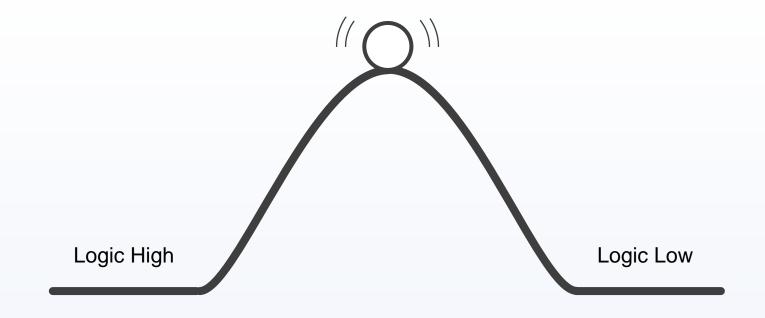
• The time constant τ is a function of the flip-flop's transconductance.

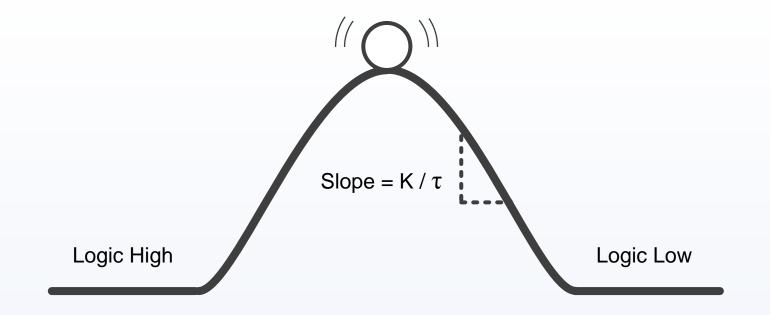
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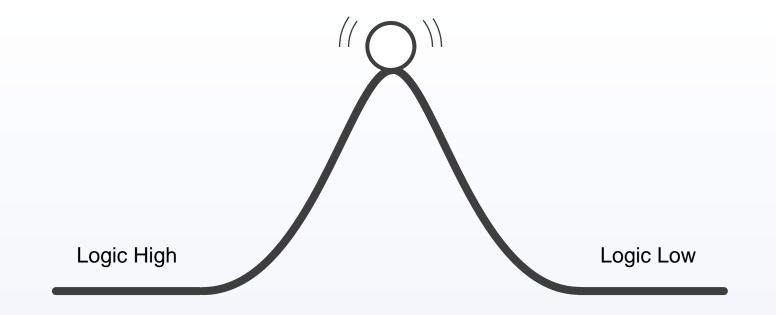
 The probability that the flip-flop's clock-to-q delay will exceed *t* seconds depends exponentially on the value of the time constant Tau.

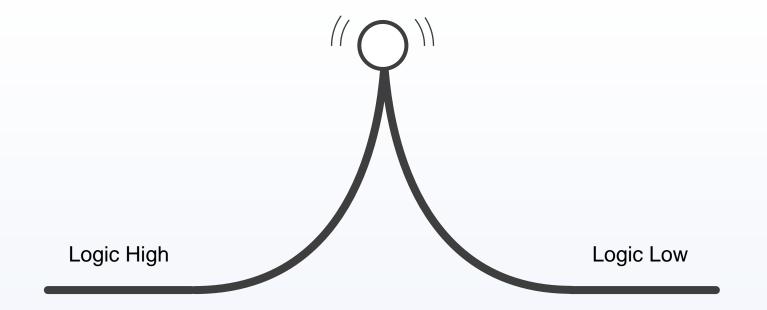


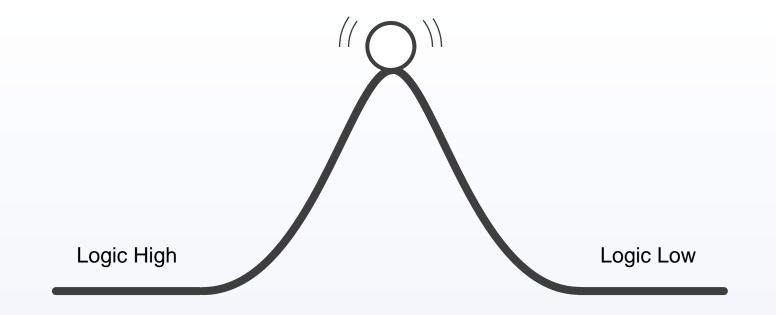


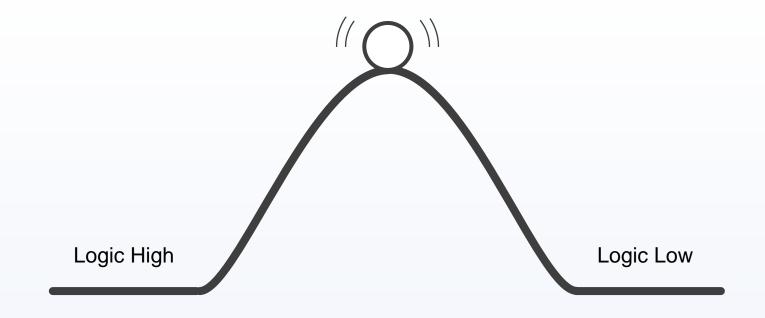






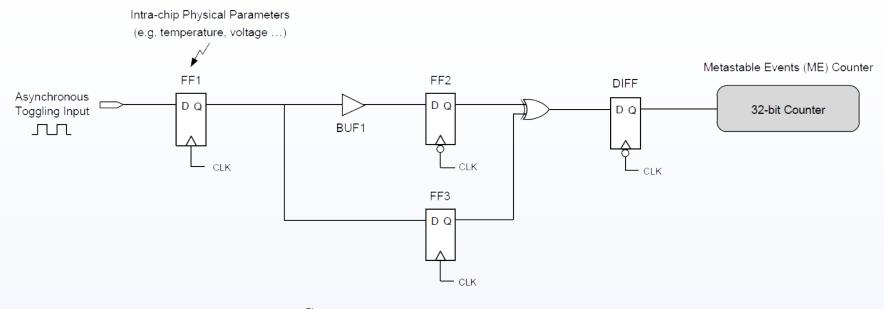






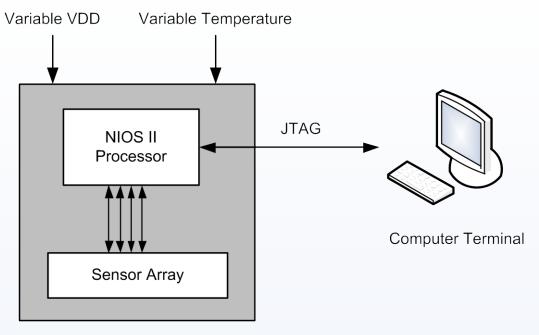
- Tau (the slope of the hill) is a function of the cross-coupled gates transconductance.
- Tau is influenced by physical parameter variations similar to propagation delay.

Proposed Design:

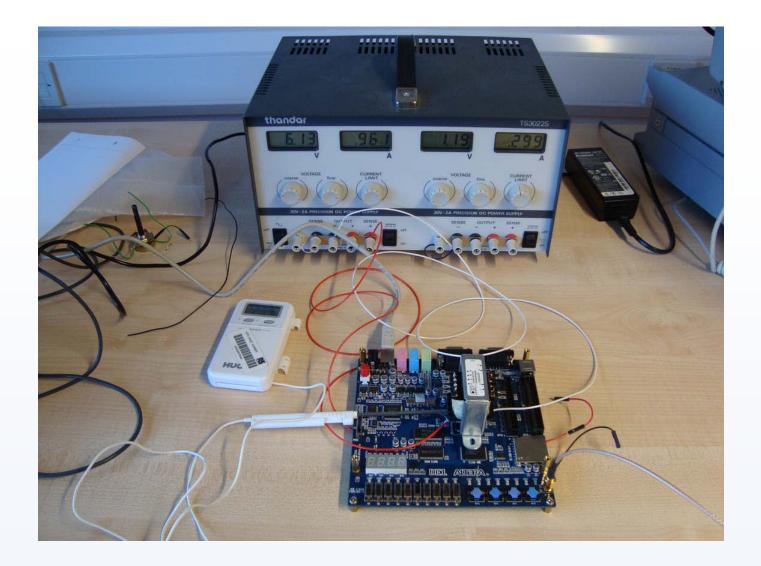


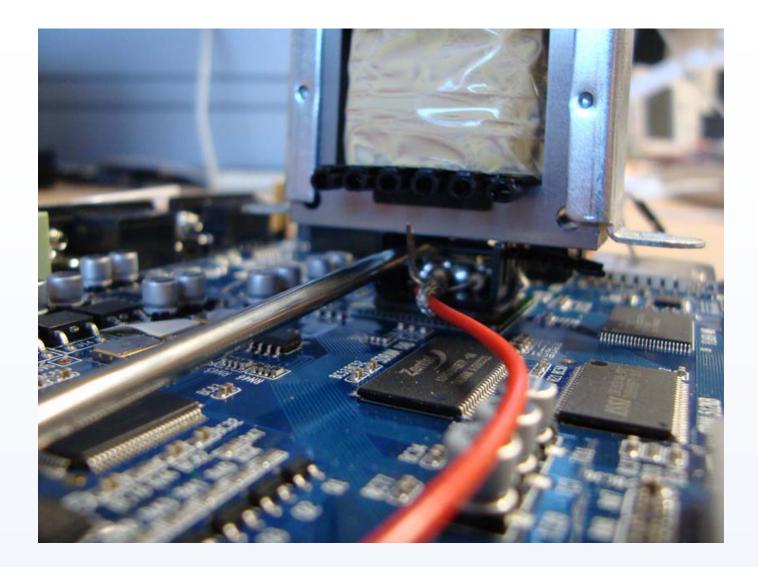
 $Count = n \times K \times e^{Sp}$

• Sensor characterization system:



Altera Cyclone II 2C20 FPGA

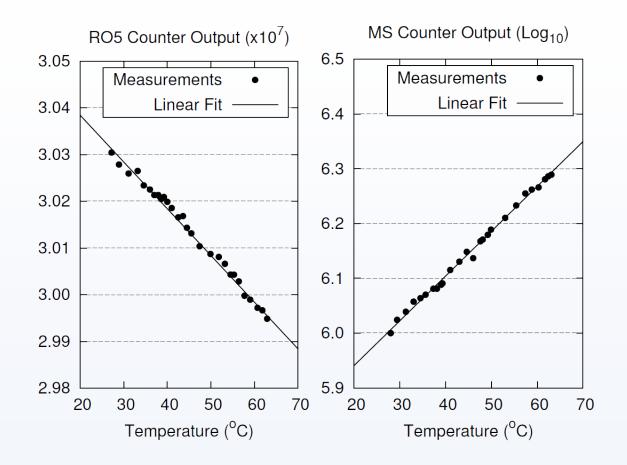




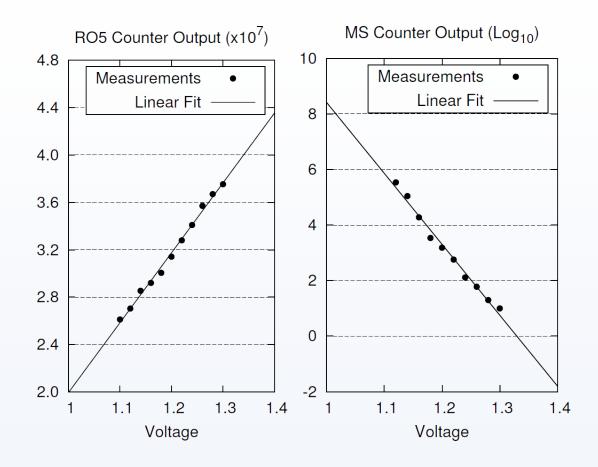
• Compared Sensors:

| Sensor | Description | LUTs | FFs |
|--------|---------------------------------------|------|-----|
| R05 | 5-stage RO with 3 decimation stages | 9 | 5 |
| R011 | 11-stage RO with 3 decimation stages | 15 | 5 |
| R017 | 17-stage RO with 3 decimation stages | 21 | 5 |
| MS | metastability-based sensor (proposed) | 2 | 4 |

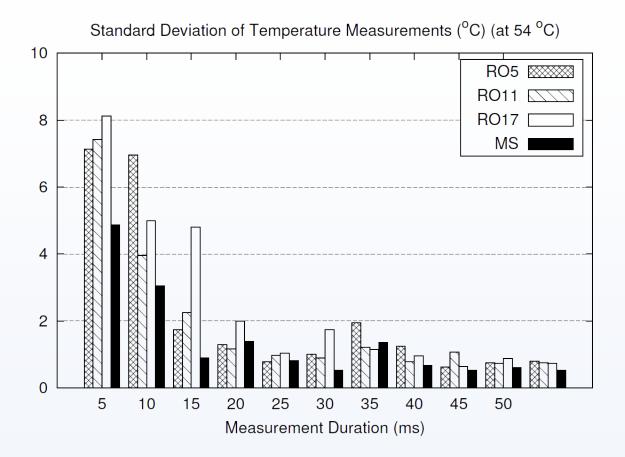
• Output Response (Temperature):



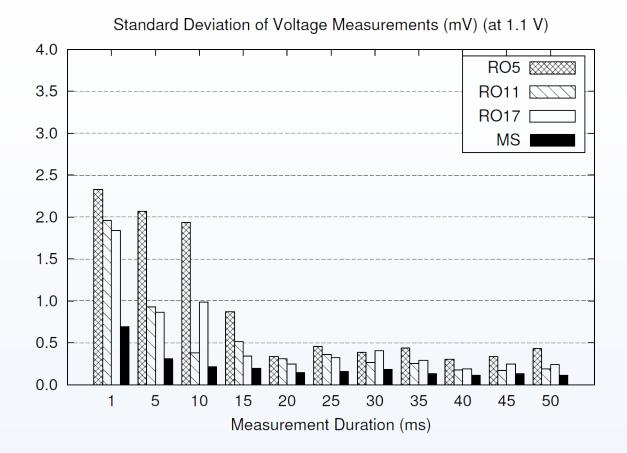
• Output Response (Voltage):



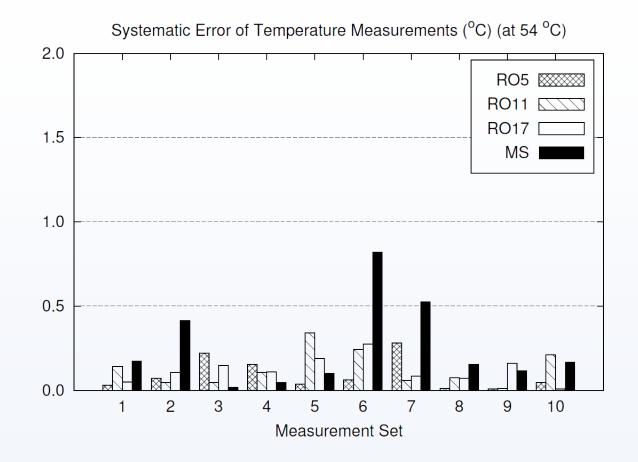
• Precision (Temperature): 60% average increase



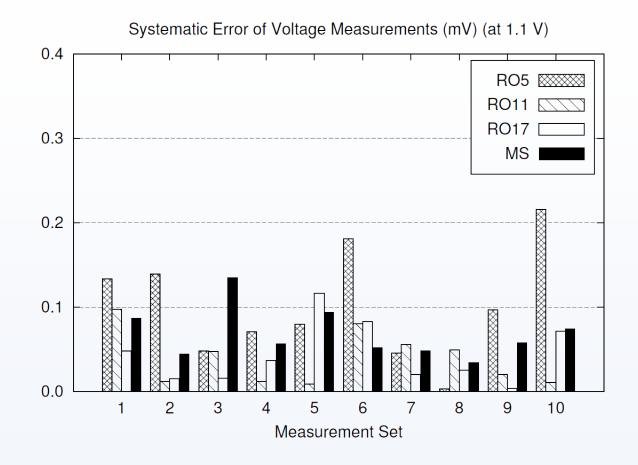
• Precision (Voltage): 173% average increase



Accuracy (Temperature): no significant difference



• Accuracy (Voltage): no significant difference



Conclusion

- Physical parameter sensing supports adaptive, reconfigurable and self-aware applications.
- Presented a novel intra-chip physical parameter sensor based on the phenomenon of flip-flop metastability.
- Proposed design consumes 20% less flip-flops, 75% less LUTs and demonstrated precision improvements of 60% in temperature sensing and 173% in voltage sensing.

End of Presentation